

Abstract Submitted  
for the MAR11 Meeting of  
The American Physical Society

**Electron spin coherence and electron nuclear double resonance of Bi donors in natural Si** JOHN MORTON, STEPHANIE SIMMONS, RICHARD GEORGE, Oxford University, WAYNE WITZEL, Sandia National Labs, H. RIEMANN, NIKOLAI ABROSIMOV, N. NOTZEL, Institute for Crystal Growth, Berlin, MIKE THEWALT, Simon Fraser University — We have shown that the electron spin coherence times of Si:Bi donors in natural silicon are limited by the same mechanism of spectral diffusion as seen in Si:P, though the smaller Bohr radius of the Bi donor leads to  $\sim 30\%$  longer  $T_2$  times (up to 0.8 ms). We have mapped out the 36 ENDOR transitions observable at X-band arising from the  $I = 9/2$  nuclear spin of  $^{209}\text{Bi}$ , going up to 1.3 GHz. We also demonstrate the transfer of electron spin coherence to and from the  $^{209}\text{Bi}$  nuclear spin with a fidelity of  $\sim 63\%$ . Using pulsed ESR at W-band (100 GHz), we observe optically-induced dynamic nuclear polarisation, consistent with the mechanism of exciton capture proposed in by T. Sekiguchi *et al.*. Finally, we explore the zero-field splitting of 7.5 GHz in this system, within the context of coupling to superconducting resonators.

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Date submitted: 10 Dec 2010

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